

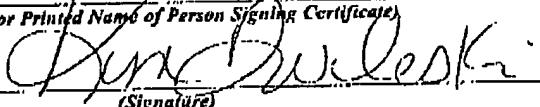
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|---|---------------------------|---------------------------------|-------------------------------|
| CERTIFICATE OF TRANSMISSION BY FACSIMILE (37 CFR 1.8) Applicant(s): Ng et al. | | | Docket No. END920030086US1 |
| Application No. 10/713,227 | Filing Date 11/13/2003 | Examiner Novacek, Christy L. | Group Art Unit 2822 |
| Invention: METHOD AND STRUCTURE TO USE AN ETCH RESISTANT LINER ON TRANSISTOR GATE STRUCTURE TO ACHIEVE HIGH DEVICE PERFORMANCE | | | |
| <p>I hereby certify that this <u>Amendment (12 pages)</u> (Identify type of correspondence) is being facsimile transmitted to the United States Patent and Trademark Office (Fax. No. <u>571-273-8300</u>) on <u>1/17/2006</u> (Date)</p> <p><u>Kim Dwileski</u> (Typed or Printed Name of Person Signing Certificate)  (Signature)</p> <p>Note: Each paper must have its own certificate of mailing.</p> | | | |

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Docket No.: END920030086US1

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Hung Y. Ng

)Examiner: Novacck, Christy L.

Serial No.: 10/713,227

)Art Unit: 2822

Filing Date: 11/13/2003

Title: METHOD AND STRUCTURE TO USE AN ETCH RESISTANT LINER ON
TRANSISTOR GATE STRUCTURE TO ACHIEVE HIGH DEVICE PERFORMANCE

Commissioner For Patents
P.O. Box 1450
Alexandria, VA 22313-1450

AMENDMENT

Sir:

In response to the Final Office Action mailed December 19, 2005, please amend the
above-identified patent application as follows:

10/713,227

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